

Scientific Questions

- What is key to understand charge carrier dynamics under non-equilibrium conditions?
- Are local relaxation and non-local / transport effects determined by identical or different microscopic processes?
- What is happening at interfaces?
- What is the influence on the excited charge carrier density n ?
- How does the static electronic structure $E(k)$ affect the non-equilibrium dynamics
- How does a particular optical or THz stimulus modify the dynamics and what are the respective processes activated?

Goals

Work package 1

- Analysis of scattering processes and propagation in non-equilibrium transport along the interface normal direction
- Separation of phononic and electronic contributions
- Analysis of transport in Bloch bands in comparison to transport by hopping in staples of 2D materials

Work package 2

- Time- and angle-resolved photoemission using THz field transients
- Analysis of in-plane charge carrier transport dynamics in real time
- Linear and non-linear response
- Manipulation of the electron dynamics by modifications of the static electronic structure using alkali surface doping

Expected Results

Work Program

Work package 1
Time-resolved photoemission of charge carriers propagating in layered materials

Metallic heterostructures Au/Fe/MgO(001)

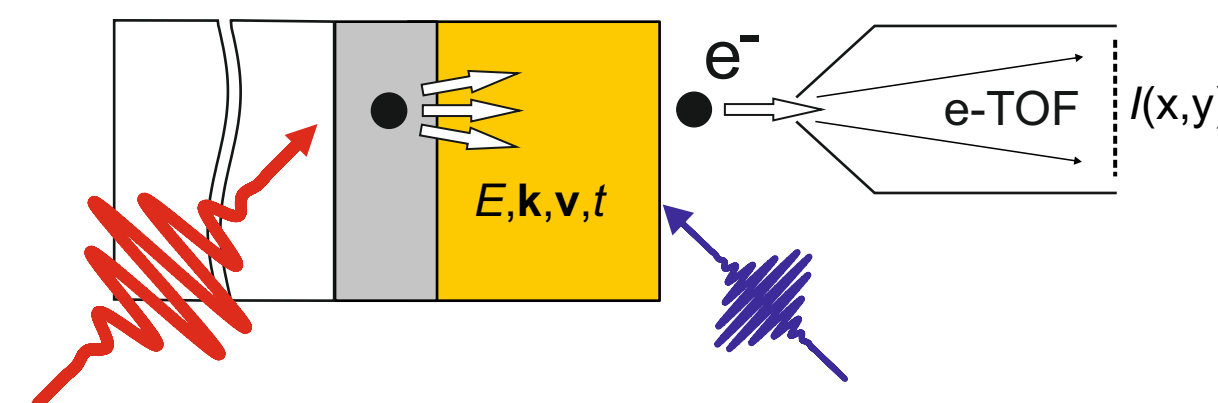
2020

- time-resolved linear photoemission using back side pumping to analyze transport effects in the vicinity of the Fermi energy (→ preliminary results)
- first steps regarding temperature dependent experiments employing back side pumping to identify phonon contributions (→ reduce sample vibration)

2021

- temperature dependent experiments (continuation)

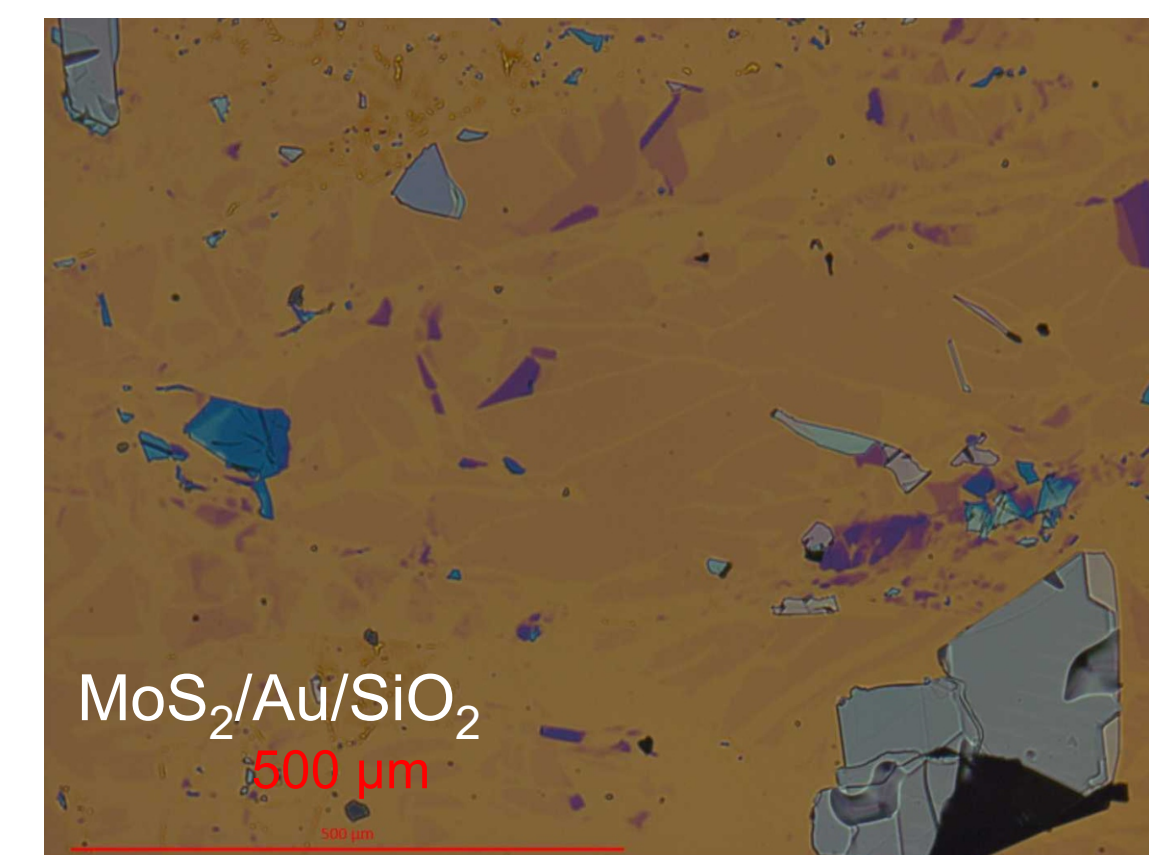
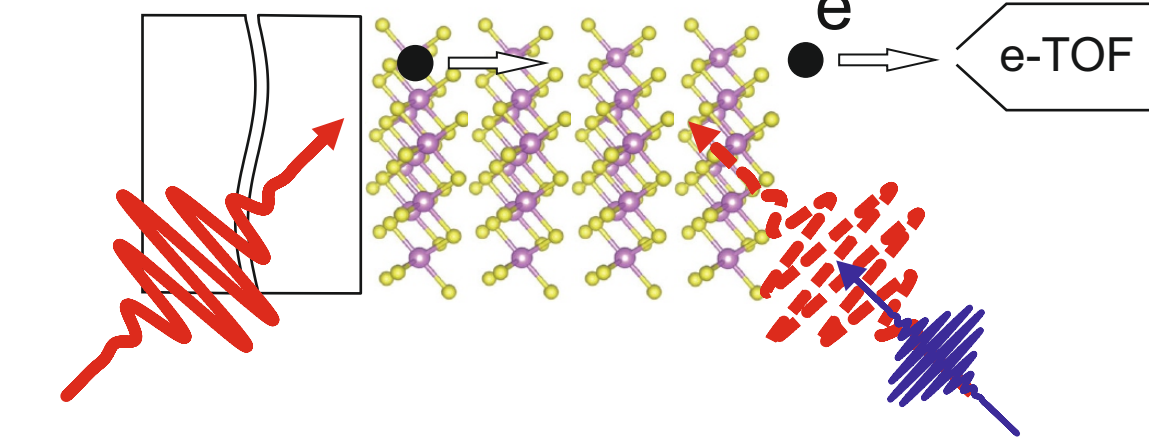
- angle-resolved experiments for ballistic electron propagation to probe elastic scattering by a position sensitive anode, see figure for interface transmittance at Fe/Au(001)



2022

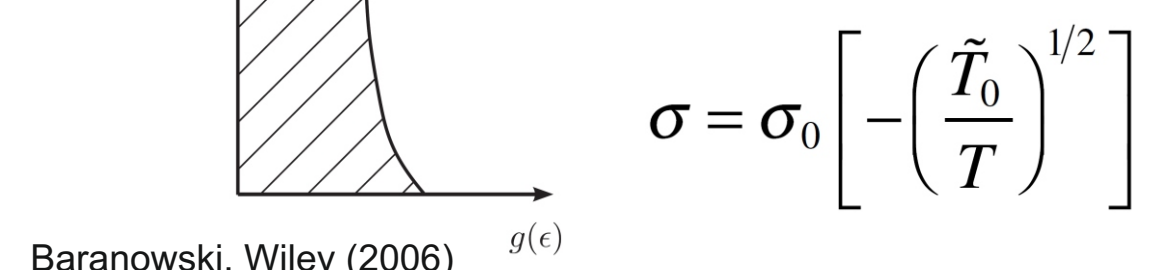
Stacks of two-dimensional materials MoS₂, MoSe₂, and TaS₂ upon back side pumping

- Sample preparation by exfoliation on thin Au films on transparent substrates (collaboration with project C05)
- Temperature dependent experiments to analyze hopping probability



2023

- Analysis of thermally activated charge carrier transport mediated by hopping, e.g. electric conductivity σ for temperature dependent variable range hopping with a parabolic energy gap



- Energy and temperature dependent transport of non-equilibrium carriers

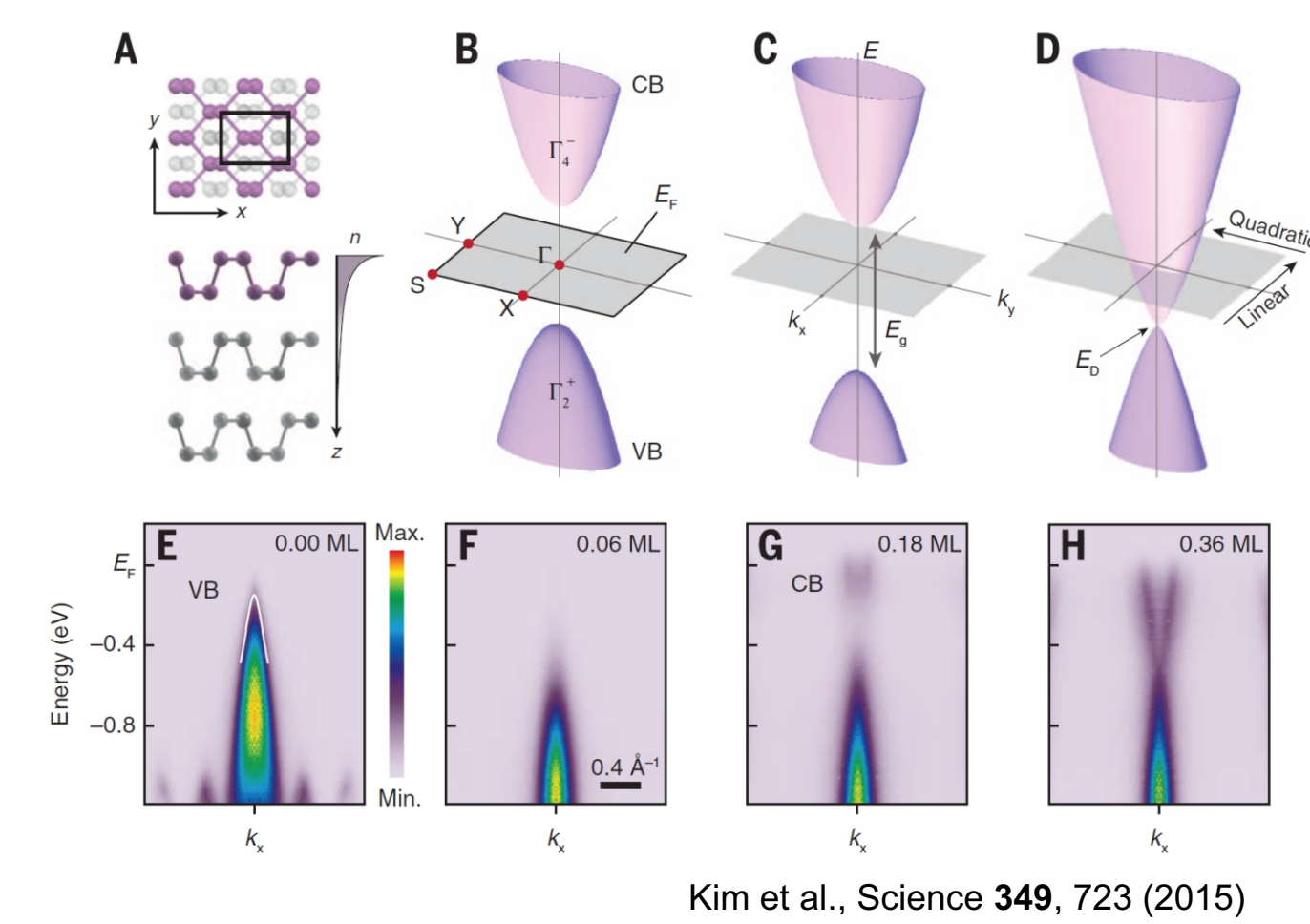
Work package 2
Real-time analysis of THz driven charge currents in surfaces of black phosphorus

2020

- Optimization of THz generation using photoconductive antenna emitter and Ti:sapphire RegA @ 100 kHz → gating of bias voltage to limit dc heating of antennae, reach peak field >50 kV/cm → funding application for gated pulse generator and voltage amplifier
- Laser ARPES of black phosphorus

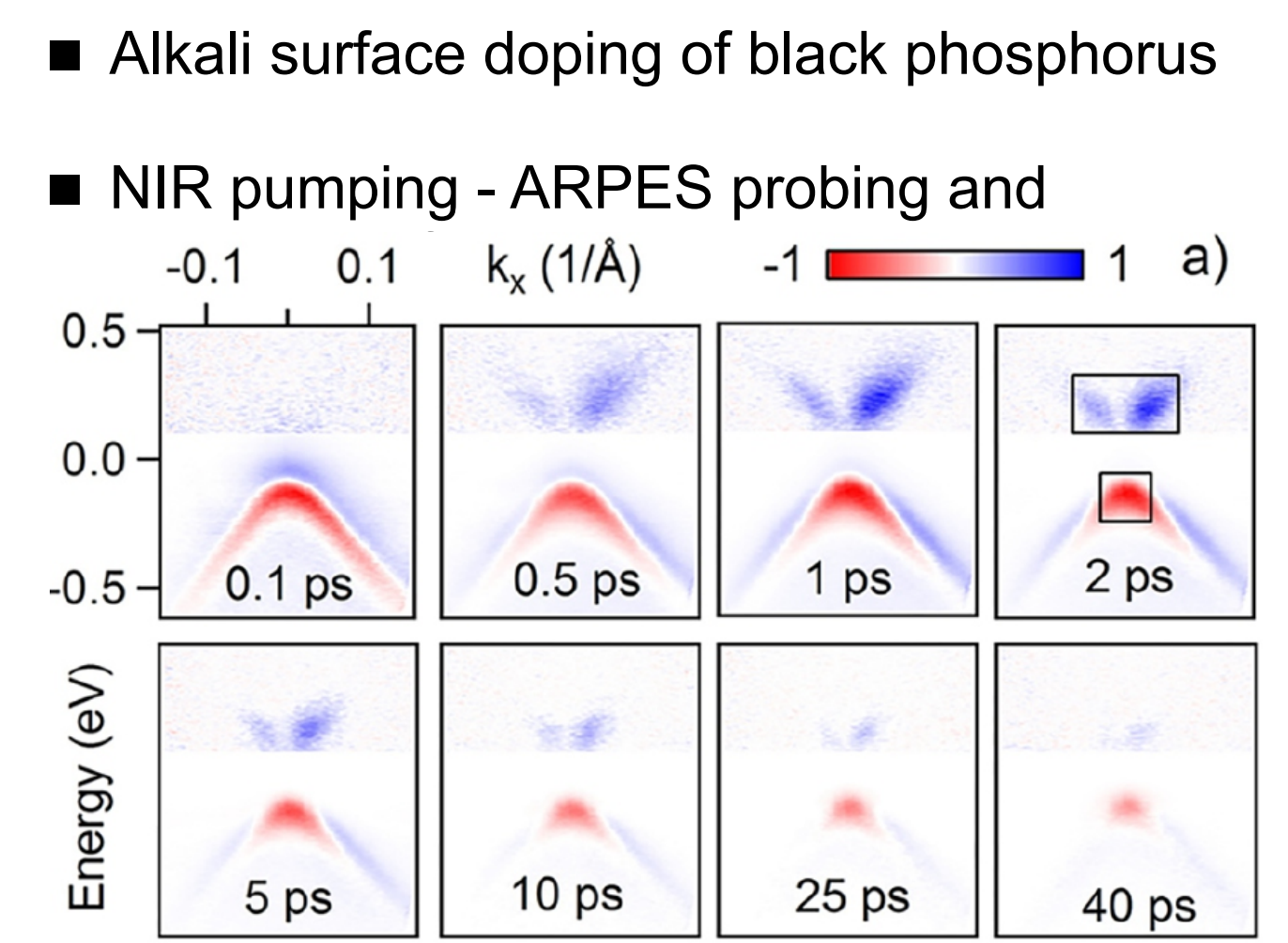
2021

- Alkali surface doping of black phosphorus Band inversion by giant Stark effect



- NIR pumping - ARPES probing of black phosphorus for different doping

2022



2023

- THz pump ARPES probe experiments
- Analysis of electron dynamics near E_F for variation of $E(k)$ by alkali doping along armchair and zigzag directions
- Manipulation of non-equilibrium electron dynamics by alkali doping
- Linear to non-linear crossover in response to THz driving the electron system

Cross Linking and Collaboration

Lattice dynamics and ultrafast diffraction

C01

Sokolowski-Tinten

B04

Horn-von Hoegen

C03

Samples of 2D materials, e.g., TaS₂, MoS₂

C05

Schleberger, Sokolowski-Tinten, Wucher

Generation of THz field transients

B09

Mittendorf

Complementary experiments on electron dynamics at interfaces

A07

Eschenlohr

A06

Campen

B06

Meyer zu

Ollefs

Hasselbrink, Tong

Heringdorf

Model calculations of propagating electronic excitations

A02

König, Sothmann

Dynamics by *ab initio* methods

B02

Gruner, Pentcheva

C02

Kratzer

Modeling non-equilibrium dynamics

B03

König, Kratzer, Schützhold

B07

Preliminary Work

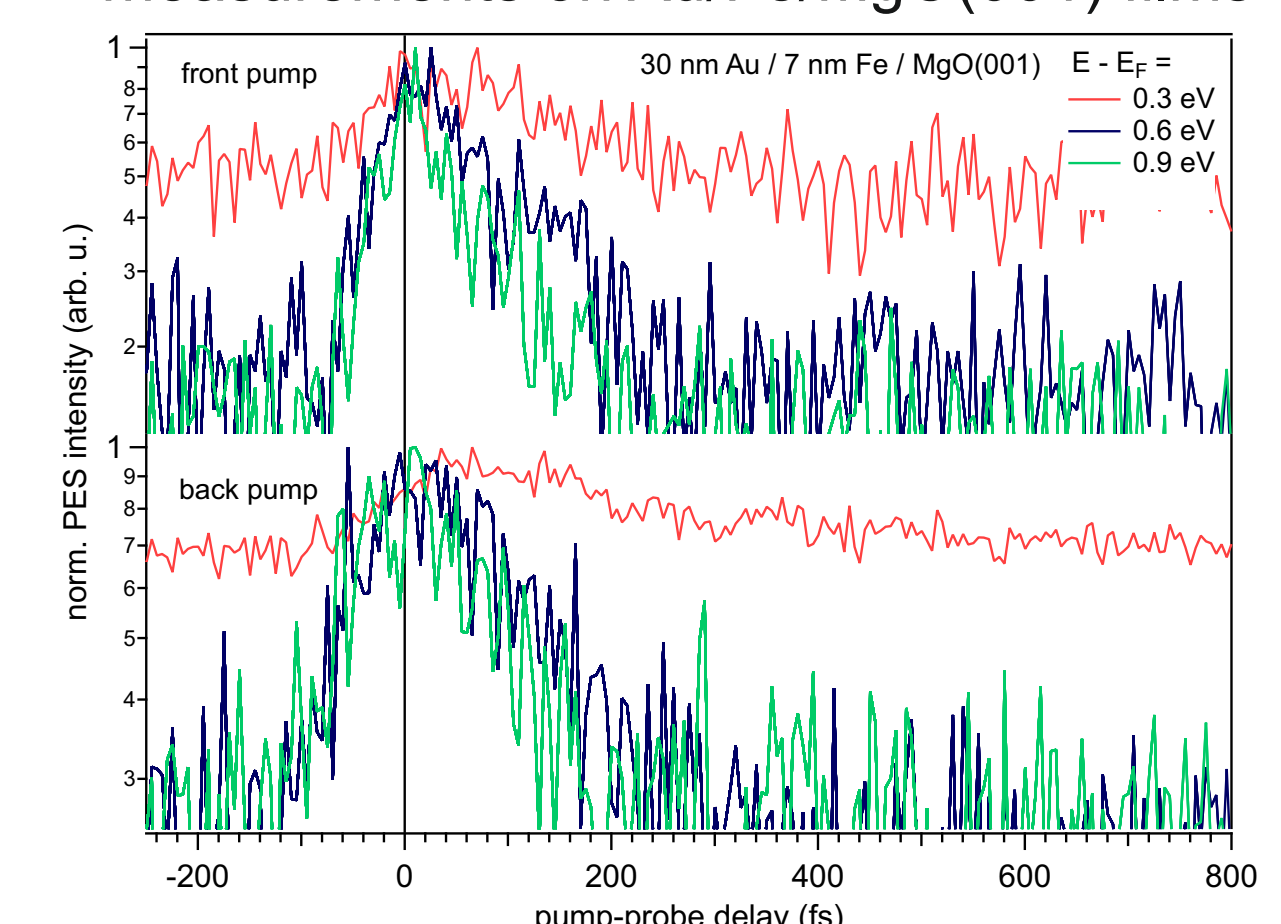
- Results obtained by 2PPE presents **superdiffusive propagation** behaviour of hot e's due to fast scattering processes at energies $E-E_F = 0.6 - 2.0$ eV

- **Idea:** exciting hot e's close to Fermi edge E_F to see mainly ballistic propagating hot e's due to longer relaxation times

- time dependent anomalous diffusion constant d_a , governed by variance σ^2 of the displacement of a single particle distribution:
$$d_a(t) = \frac{2}{t} \frac{\sigma^2}{d\sigma^2/dt}$$
 - $d_a = 1$: ballistic propagation
 - $1.5 < d_a < 2$: superdiffusive regime
 - $d_a = 2$: diffusive regime

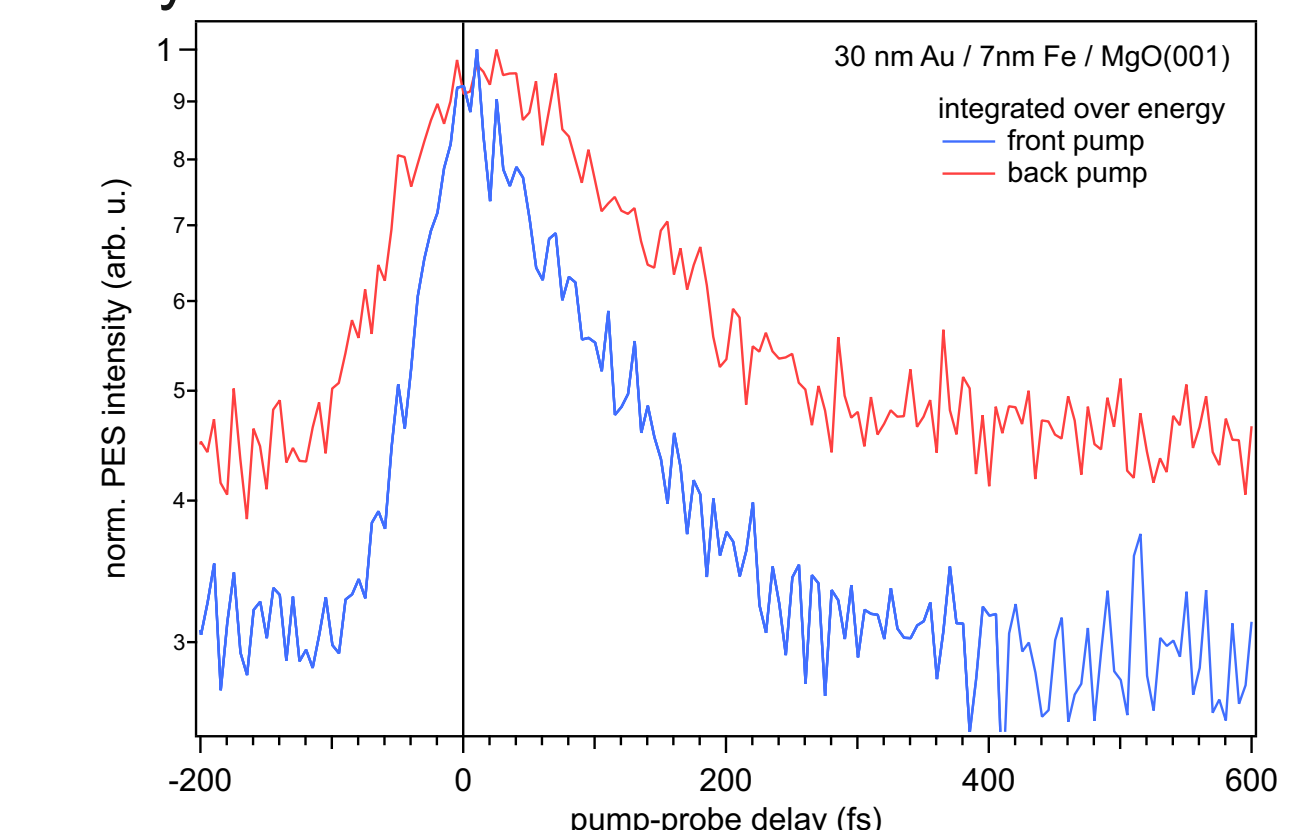
For short times, $t \ll \tau$, motion is mainly ballistic and the particle experiences approximately no scatterings. On times, $t \gg \tau$, many scatterings appear and the overall motion is well approximated by standard diffusion.

- **First** results with front and back side pumping linear photoemission measurements on Au/Fe/MgO(001) films



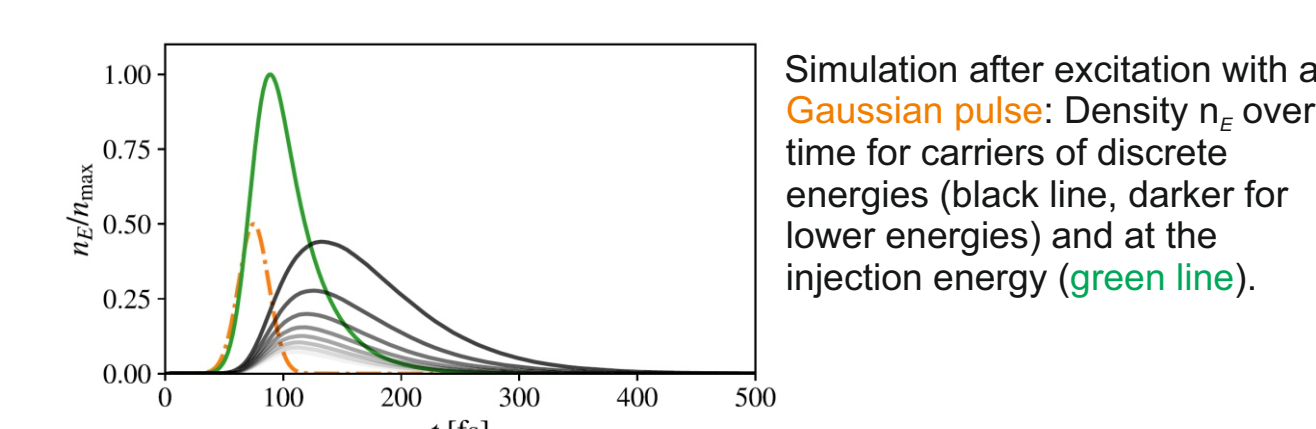
- Observation of differences in population dynamics at a given energy $E-E_F$ hardly to see
- transport effects less obvious due to time independent signal background

- **But:** integration over an energy range of $E-E_F = 0 - 1.55$ eV reveals a clear contrast in pump-probe signal and relaxation dynamics



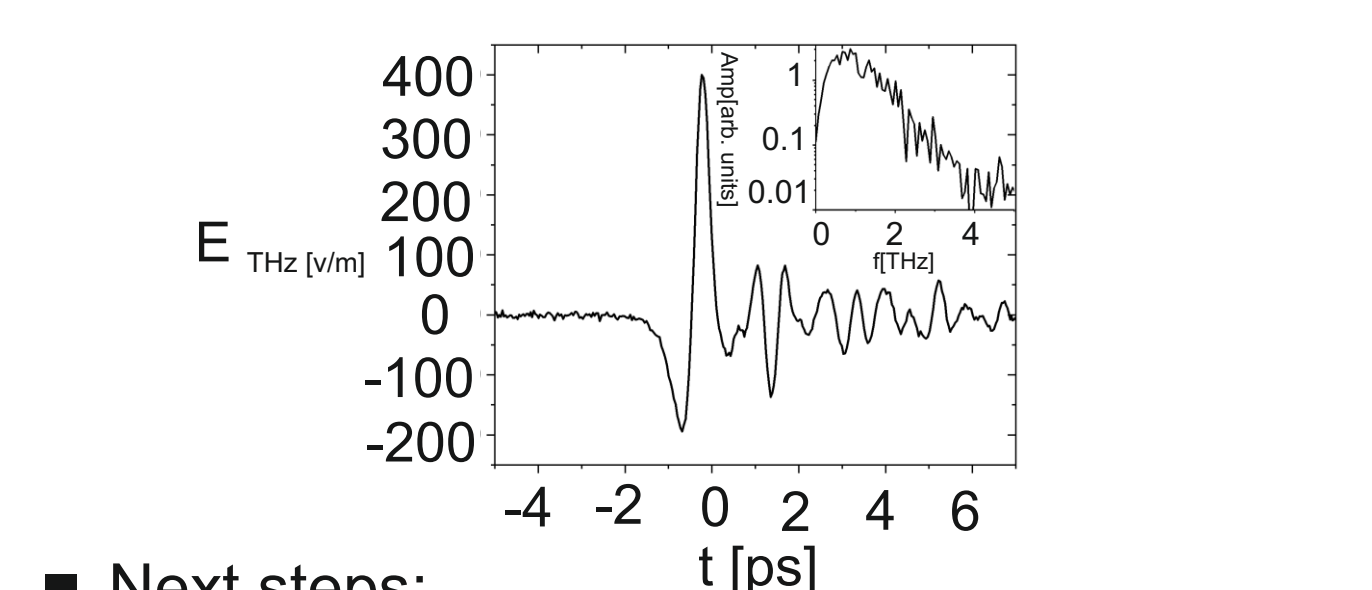
- back pump: small delayed shift in peak intensity and broadening in population dynamics → signature for transport?

- Nenno et al., PRB 98, 224416 (2018): delayed shift and broadening of particle densities at lower energies due to spatiotemporal transport and scattering processes



- Generation of THz pulse to investigate realtime charge transport using a THz-pump photoemission-proBiasbe experiment by using a photoconductive (PC) antenna. This part is implemented by collaboration with project B09.

- The generated THz field with 400 V/m amplitude with the near-IR fiber laser (780 nm, 80 MHz) of energy per pulse of 1.4 nJ:



- Next steps:
1- Increasing energy per pulse to 4 uJ by using RegA 9040 pulsed laser (800 nm, 250 kHz).
2- Increasing bias voltage.

- Challenges and solutions:
1- Excessive heating of the PC (solution: using a pulse generator and an amplifier).

- 2- Increasing the size of the PC emitters (solution: optimization of the THz pulse by using different PCs).